

INTELLIGENT POWER HIGH SIDE SWITCH

Features

- Over temperature shutdown (with auto-restart)
- Short circuit protection (current limit)
- Active clamp
- Open load detection
- Logic ground isolated from power ground
- ESD protection
- Ground loss protection
- Status feedback

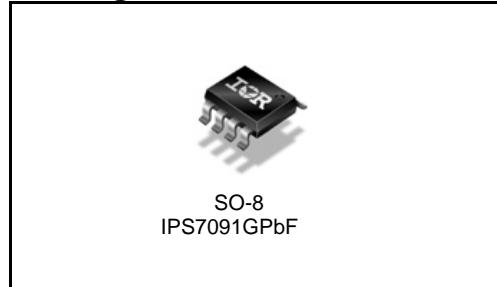
Product Summary

Rds(on)	120mΩ max.
Vclamp	70V
I Limit	5A (typ.)
Open load	3V

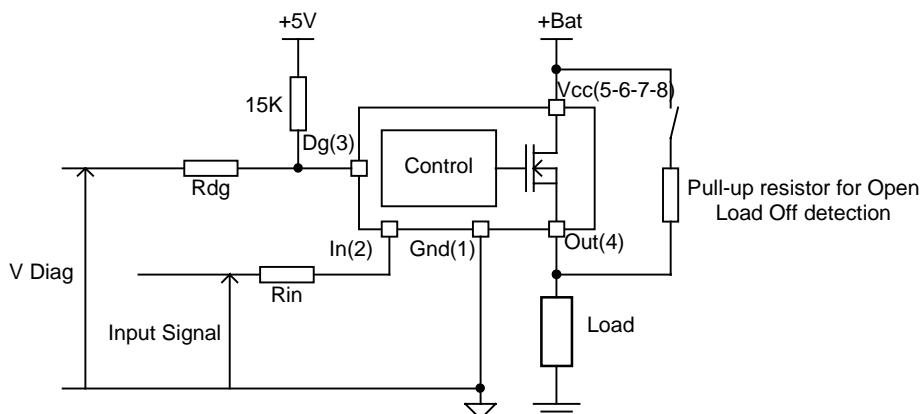
Description

The IPS7091GPbF is a five terminal Intelligent Power Switch (IPS) with built in short circuit, over-temperature, ESD protection, inductive load capability and diagnostic feedback. The output current is limited at I_{lim} value. Current limitation is activated until the thermal protection acts. The over-temperature protection turns off the device if the junction temperature exceeds $T_{shutdown}$. It will automatically restart after the junction has cooled 7°C below $T_{shutdown}$. A diagnostic pin is provided for status feedback of short circuit, over-temperature and open load detection. The double level shifter circuitry allows large offsets between the logic ground and the load.

Package



Typical Connection



Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are referenced to Ground lead. (T_{ambient}=25°C unless otherwise specified).

Symbol	Parameter	Min.	Max.	Units
V _{out}	Maximum output voltage	V _{cc} -65	V _{cc} +0.3	
V _{offset}	Maximum logic ground to load ground offset	V _{cc} -65	V _{cc} +0.3	
V _{in}	Maximum input voltage	-0.3	5.5	V
V _{cc} max.	Maximum V _{cc} voltage	—	65	
V _{cc} cont.	Maximum continuous V _{cc} voltage	—	35	
I _{IN} max.	Maximum IN current	-1	10	mA
I _{DG} max.	Maximum diagnostic output current	-1	10	
V _{DG}	Maximum diagnostic output voltage	-0.3	5.5	V
P _d	Maximum power dissipation (internally limited by thermal protection) R _{th} =100°C/W	—	1.25	W
I _{SD} cont.	Maximum continuous diode current (R _{th} =100°C/W)	—	1.8	A
ESD1	Electrostatic discharge voltage (Human body) 100pF, 1500Ω	—	4	kV
ESD2	Electrostatic discharge voltage (Machine Model) C=200pF, R=0Ω, L=10μH	—	0.5	
T _j max.	Max. storage & operating temperature junction temperature	-40	+150	°C

Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Units
R _{th1}	Thermal resistance junction to ambient SO8 std. footprint	100	—	°C/W

Recommended Operating Conditions

These values are given for a quick design. For operation outside these conditions, please consult the application notes.

Symbol	Parameter	Min.	Max.	Units
V _{IH}	High level input voltage	4	5.5	
V _{IL}	Low level input voltage	-0.3	0.9	
I _{out}	Continuous drain current, T _{amb} =85°C, T _j =125°C, V _{in} =5V, R _{th} =100°C/W	—	1.5	A
R _{IN}	Recommended resistor in series with IN pin	4	10	
R _{DGS}	Recommended resistor in series with DG pin	10	20	kΩ
R _{OL}	Recommended pull-up resistor for open load detection	5	100	

Static Electrical Characteristics

T_j=25°C, V_{cc}=14V (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
R _{ds(on)}	ON state resistance T _j =25°C	—	80	120	mΩ	V _{in} =5V, I _{out} =2A
	ON state resistance T _j =150°C	—	150	230		V _{in} =5V, I _{out} =2A
	ON state resistance T _j =25°C, V _{cc} =6V	—	90	130		V _{in} =5V, I _{out} =2A
V _{cc op.}	Operating voltage range	6	—	35	V	
V clamp 1	V _{cc} to Out clamp voltage 1	65	70	—		I _{out} =30mA (see Fig. 1)
V clamp 2	V _{cc} to Out clamp voltage 2	—	70	75		I _{out} =1A (see Fig. 1)
V _f	Body diode forward voltage	—	1	1.35		I _{out} = 2.5A
I _{cc Off}	Supply current when Off	—	5	50	μA	V _{in} =0V, V _{out} =0V
I _{cc On}	Supply current when On	—	2.5	3.5	mA	V _{in} =5V
I _{out@0V}	Output leakage current	—	—	25	μA	V _{out} =0V
I _{out@6V}	Output leakage current	—	20	—		V _{out} =6V
I _{dg leakage}	Diagnostic output leakage current	—	—	10		V _{dg} =5.5V
V _{dg1}	Low level diagnostic output voltage	—	0.2	0.3	V	I _{dg} =1.6mA
V _{ih}	Input high threshold voltage	—	2.5	3.5		
V _{il}	Input low threshold voltage	1	2	—		
In hys	Input hysteresis	0.15	0.4	1		
UV high	Under voltage high threshold voltage	—	5	5.9		
UV low	Under voltage low threshold voltage	3.4	4.5	—		
UV hys	Undervoltage hysteresis	0.1	0.8	1.5		
I _{in On}	Input current when device is On	—	40	80	μA	V _{in} =5V

Switching Electrical Characteristics

V_{cc}=14V, Resistive load=14Ω, V_{in}=5V, T_j=25°C

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
T _{d0n}	Turn-on delay time	—	12	35	μs	See Fig. 3
T _{r1}	Rise time to V _{out} =V _{cc} -5V	—	9	40		
T _{r2}	Rise time to V _{out} =0.9 x V _{cc}	—	11	75		
dV/dt (On)	Turn On dV/dt	—	0.95	3.5		
E _{On}	Turn On energy	—	250	—		
T _{d0ff}	Turn-off delay time	—	20	45		
T _f	Fall time to V _{out} =0.1 x V _{cc}	—	6	25		
dV/dt (Off)	Turn Off dV/dt	—	1.8	5.5		
E _{Off}	Turn Off energy	—	20	—		
T _{diag}	V _{out} to V _{diag} propagation delay	—	15	—	μs	See Fig. 4 and Fig. 12

Protection Characteristics

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
Ilim	Internal current limit	2	5	8	A	Vout=0V
Tsd+	Over temperature high threshold	150 ⁽¹⁾	165	—	°C	See Fig. 2
Tsd-	Over temperature low threshold	—	158	—		
Vsc	Short-circuit detection voltage ⁽²⁾	2	3	4	V	
Vopen load	Open load detection threshold	2	3	4		

⁽¹⁾ Guaranteed by design

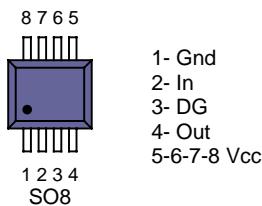
⁽²⁾ Reference to Vcc

Truth Table

Operating Conditions	IN	OUT	DG pin
Normal	H	H	H
Normal	L	L	L
Open Load	H	H	H
Open Load ⁽³⁾	L	H	H
Short circuit to Gnd	H	L (limiting)	L
Short circuit to Gnd	L	L	L
Over-temperature	H	L (cycling)	L
Over-temperature	L	L	L

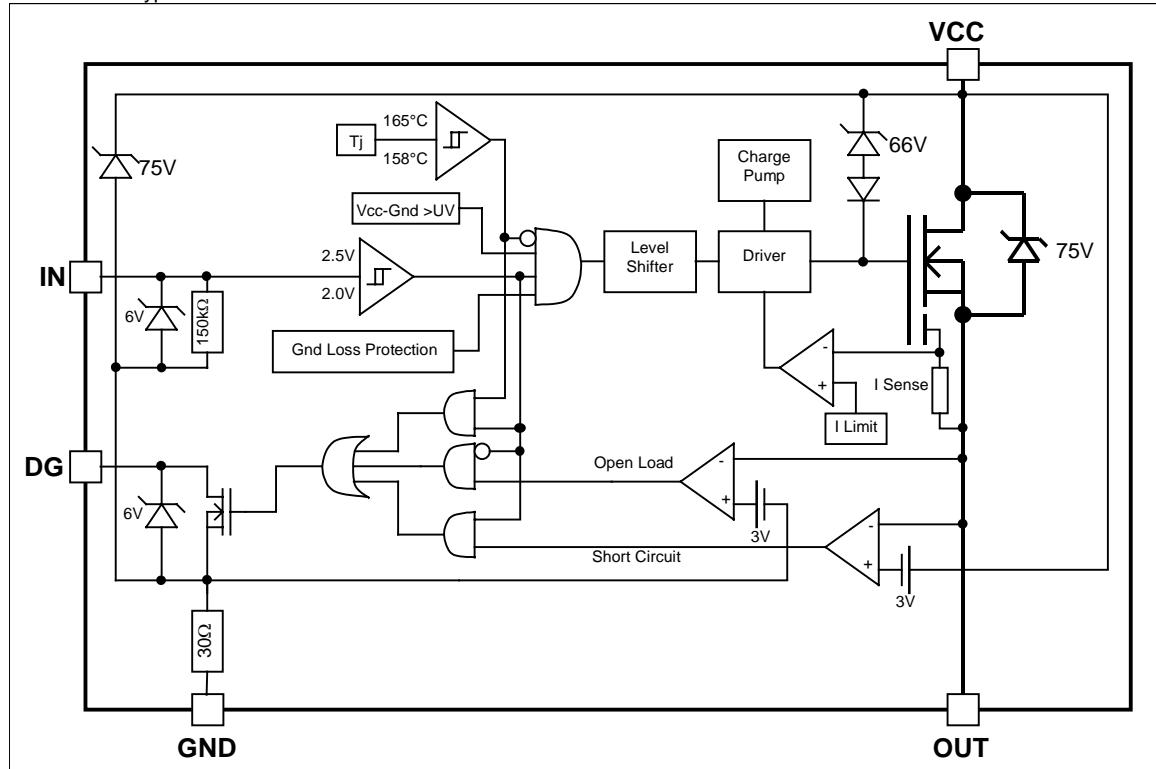
⁽³⁾ With a pull-up resistor connected between the output and Vcc.

Lead Assignments



Functional Block Diagram

All values are typical



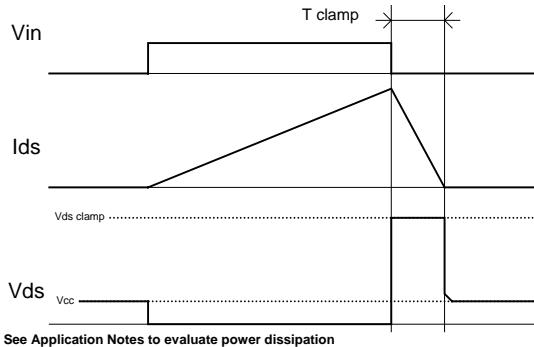


Figure 1 – Active clamp waveforms

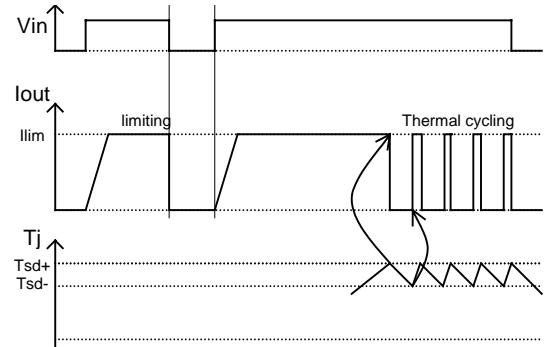


Figure 2 – Protection timing diagram

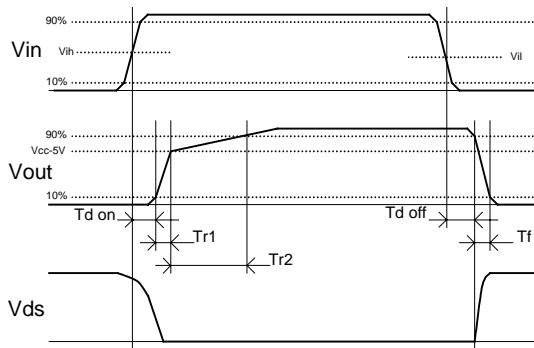


Figure 3 – Switching times definition

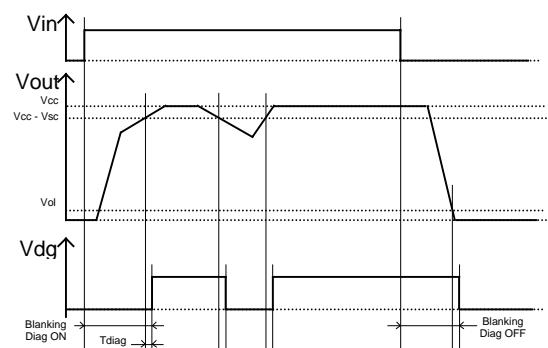


Figure 4 – Diagnostic delay definition

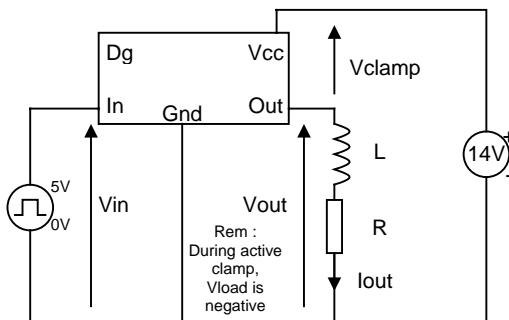


Figure 5 – Active clamp test circuit

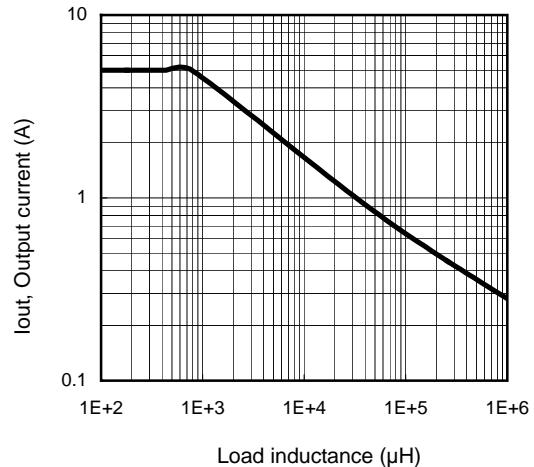


Figure 6 – Max. Output current (A) Vs Load inductance (μ H)

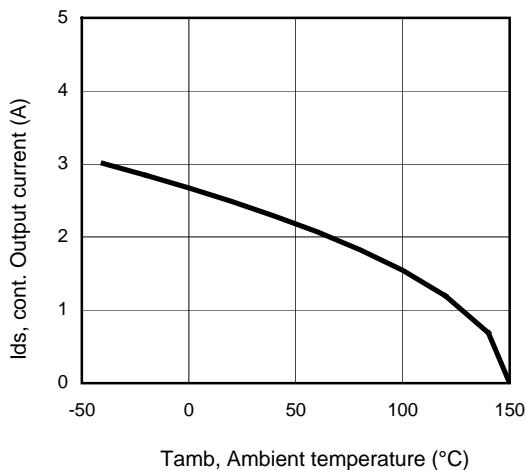


Figure 7 – Max. ouput current (A) Vs Ambient temperature (°C)

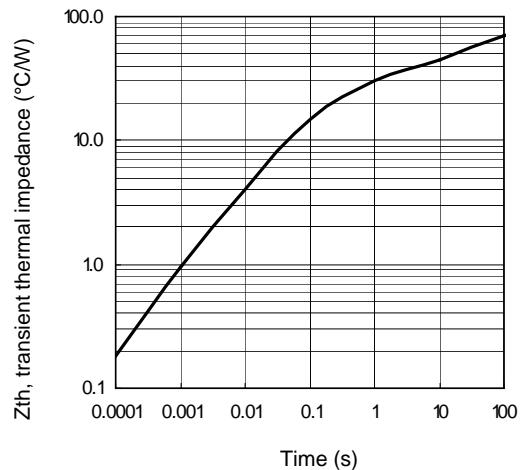
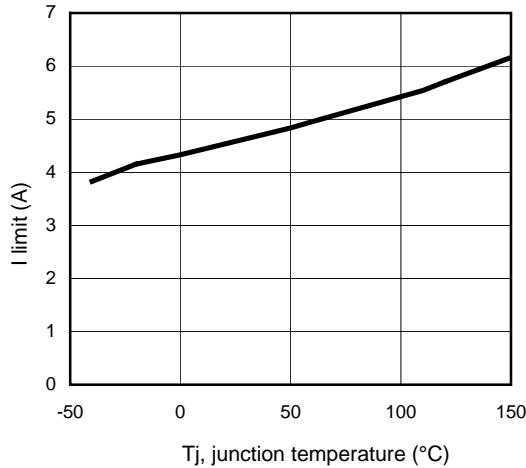
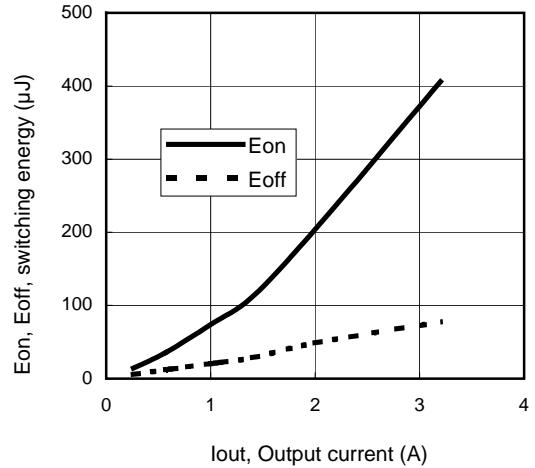


Figure 8 – Transient thermal impedance (°C/W) Vs time (s)



**Figure 9 –I limit (A)
Vs junction temperature (°C)**



**Figure 10 – Switching energy (μJ)
Vs Output current (A)**

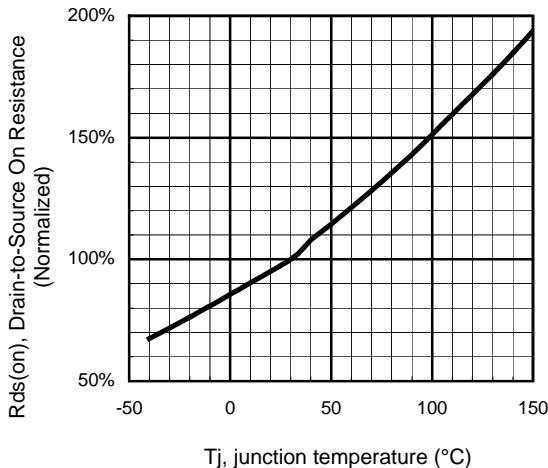
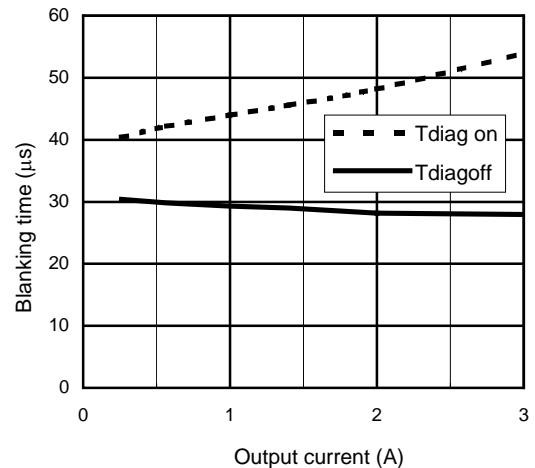


Figure 11 - Normalized Rds(on) (%) Vs T_j (°C)



**Figure 12 – Diagnosis Blanking time (μs)
Vs Output current (A)**

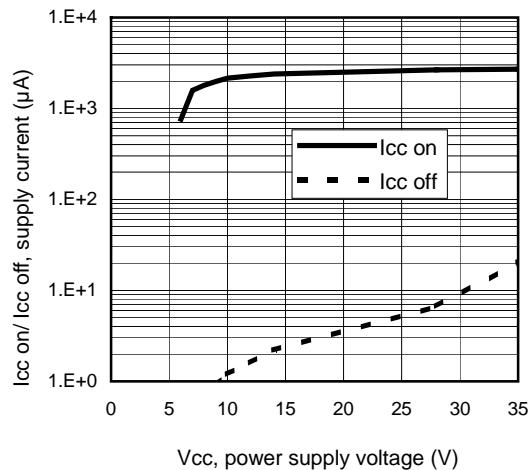


Figure 13 – $I_{CC\ on}/I_{CC\ off}$ (μA) Vs V_{CC} (V)

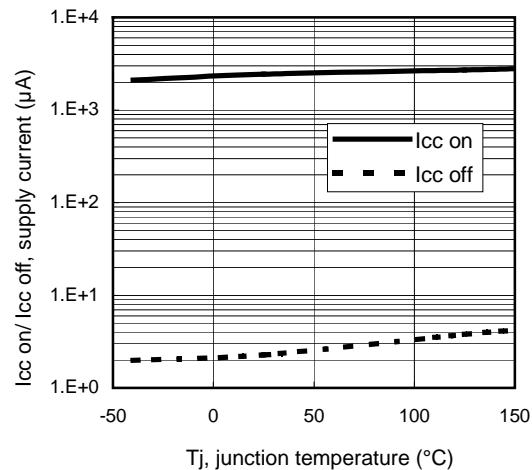
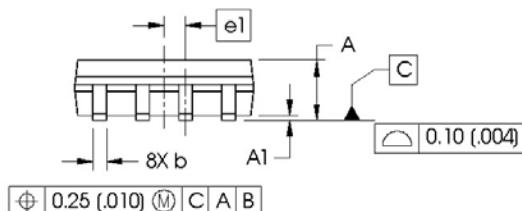
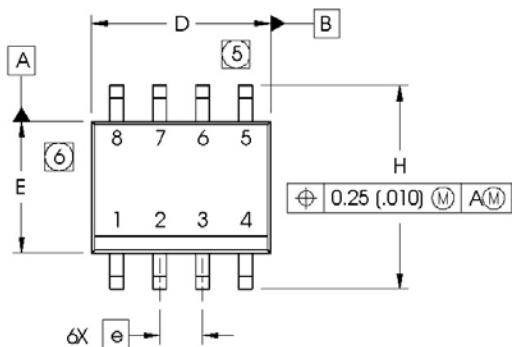


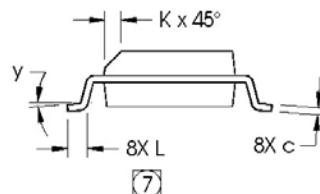
Figure 14 – $I_{CC\ on}/I_{CC\ off}$ (μA) Vs T_j ($^{\circ}C$)

Case Outline - SO-8

Dimensions are shown in millimeters (inches)

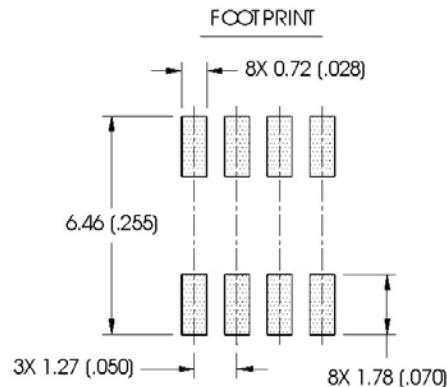


DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.0532	.0688	1.35	1.75
A1	.0040	.0098	0.10	0.25
b	.013	.020	0.33	0.51
c	.0075	.0098	0.19	0.25
D	.189	.1968	4.80	5.00
E	.1497	.1574	3.80	4.00
e	.050	BASIC	1.27	BASIC
e1	.025	BASIC	0.635	BASIC
H	.2284	.2440	5.80	6.20
K	.0099	.0196	0.25	0.50
L	.016	.050	0.40	1.27
Y	0°	8°	0°	8°

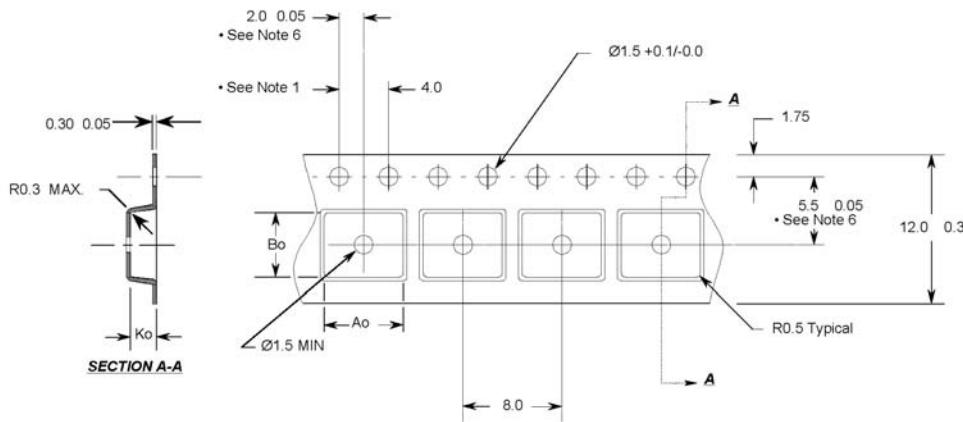


NOTES:

1. DIMENSIONING & TOLERANCING PER ASME Y14.5M-1994.
2. CONTROLLING DIMENSION: MILLIMETER
3. DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).
4. OUTLINE CONFORMS TO JEDEC OUTLINE MS-012AA.
5. DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS.
MOLD PROTRUSIONS NOT TO EXCEED 0.15 (.006).
6. DIMENSION DOES NOT INCLUDE MOLD PROTRUSIONS.
MOLD PROTRUSIONS NOT TO EXCEED 0.25 (.010).
7. DIMENSION IS THE LENGTH OF LEAD FOR SOLDERING TO
A SUBSTRATE.



Tape & Reel - SO-8



Notes:

1. 10 sprocket hole pitch cumulative tolerance 0.2
 2. Camber not to exceed 1mm in 100mm
 3. Material: Black Conductive Advantek Polystyrene
 4. Ao and Bo measured on a plane 0.3mm above the bottom of the pocket
 5. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
 6. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.

$$\begin{aligned} Ao &= 6.4 \text{ mm} \\ Bo &= 5.2 \text{ mm} \\ Ko &= 2.1 \text{ mm} \end{aligned}$$

- All Dimensions in Millimeters -

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Data and specifications subject to change without notice.
SO8 is MSL2 qualified.

This product has been designed and qualified for the Automotive [Q100] market. 08/22/2006